

**TDK | 东京电子** AVR-M1608C120MT6AB **PDF**



**深圳创唯电子有限公司**

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# Chip Varistors

Countermeasure for surge voltage and static electricity

## AVR series

Type:            **AVR-M**  
                      **AVRL**

Issue date:      September 2013

- All specifications are subject to change without notice.
  - Conformity to RoHS Directive: This means that, in conformity with EU Directive 2002/95/EC, lead, cadmium, mercury, hexavalent chromium, and specific bromine-based flame retardants, PBB and PBDE, have not been used, except for exempted applications.
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# Varistors(SMD)

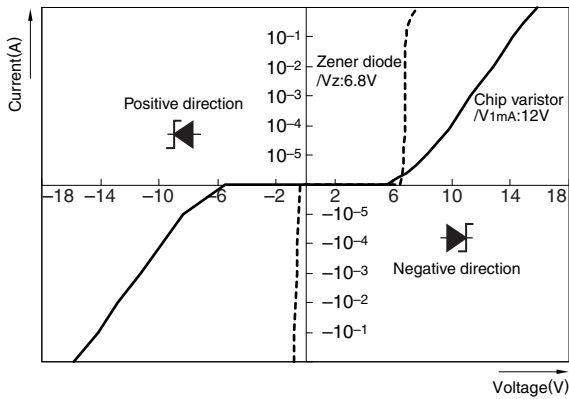
## Countermeasure for Surge Voltage and Static Electricity

### AVR Series AVR-M, AVRL Types

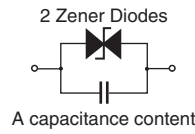
Varistors are voltage dependent nonlinear resistive elements with a resistance that decreases rapidly when the voltage is over the constant value.

Varistor is equivalent with Zener diode of two series connection. Therefore, do not have polarity.

#### CURRENT vs. VOLTAGE CHARACTERISTICS

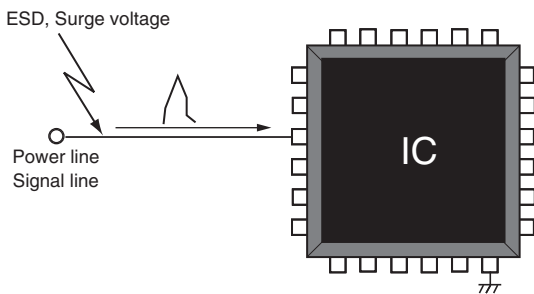


#### EQUIVALENT CIRCUIT



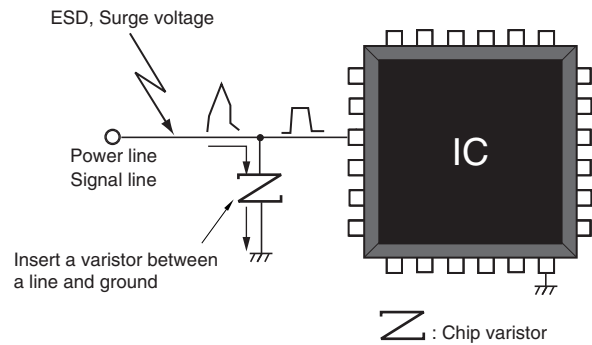
#### THE EFFECT OF THE VARISTOR WITHOUT VARISTOR

A malfunction and failure of electronic equipment



#### WITH VARISTOR

Suppress abnormal voltage by inserting varistor in a circuit



## FEATURES

- No polarity, due to symmetrical current-voltage characteristics. Equivalent to anode common type Zener diode.
- Excellent electrostatic absorption capability. Response is as good or better than Zener diode. Keeps symmetrical current-voltage characteristics even after electrostatic absorption.
- Adopted the inner electrodes lamination structure. Wide range of varistor voltages are available in series (6.8 to 39V). Low capacitance items are available in series (1.1pF to). World's smallest 0402-, 0603-, 1005-, 1608-, 2012-chip types are available in series.
- Excellent mount reliability. Good for Pb-free soldering. Adopted (Ni/Sn) electroplating. Achieved good solderability and solder heat resistance.
- Can replace a Zener diode + capacitor combination. Reduced footprint and total mounting cost.

## APPLICATIONS

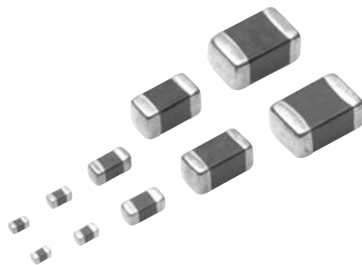
- Electrostatic absorption
- Pulse noise absorption

## TEMPERATURE RANGES

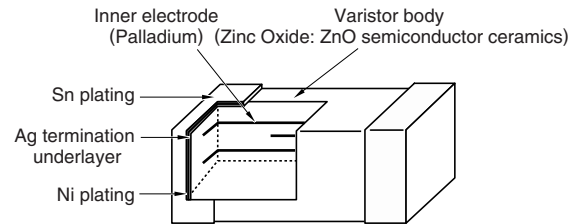
Type	AVR-M1005/1608/2012	AVR-M0402/0603/AVRL
Operating	-40 to +125°C	-40 to +85°C
Storage	-40 to +125°C	-40 to +85°C

## APPLICATION EXAMPLES

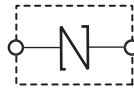
Consumer product	Application
Mobile phone	Data terminal
Digital video camera	LCD panel
Digital camera	Touch panel
PDA	Button and switch unit
Note PC	Battery terminal
DVD-ROM, CD-ROM	Audio-Video input-output terminal
CD/MD/MP3 player	Microphone/receiver unit
Game machine	Controller unit
	CAN-BUS
	ECU
In-car equipment	Connector
	Air conditioner panel
	Car audio
	Car navigation



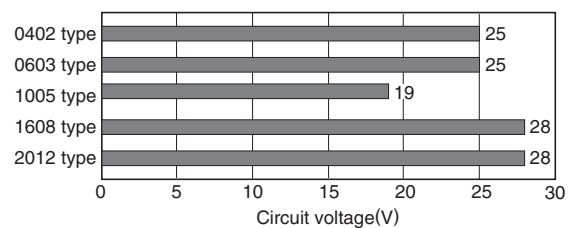
## INTERNAL STRUCTURE



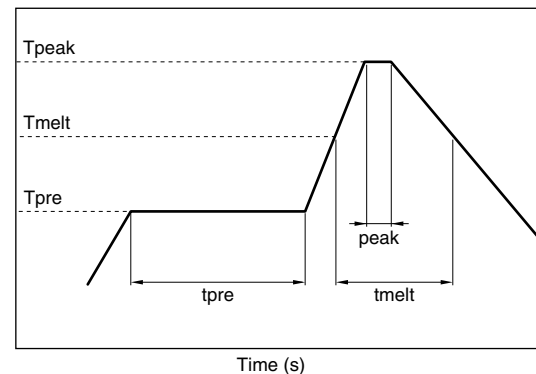
## CIRCUITS SYMBOL



## OPERATIONAL VOLTAGE RANGES



## RECOMMENDED REFLOW SOLDERING CONDITIONS



Item	Specification	Specification	
		For eutectic solder	For lead-free solder
Tpre	Preheating temperature	160 to 180°C	150 to 180°C
Tmelt	Solder melting temperature	200°C	230°C
Tpeak	Peak temperature	240°C max.	260°C max.
tpre	Preheating time	100s max.	120s max.
tmelt	Time to reach higher than the solder melting temperature	30s max.	40s max.
	Number of possible reflow cycles	2 max.	2 max.

## AVR-M TYPE

### PRODUCT IDENTIFICATION

AVR-M	1005	C	270	M	T	AAB
(1)	(2)	(3)	(4)	(5)	(6)	(7)

AVRM	1005	C	6R8	N	T	101	N
(1)	(2)	(3)	(4)	(5)	(6)	(7)	(8)

(1) Series name

(2) Dimensions L×W

0402	0.4×0.2mm
0603	0.6×0.3mm
1005	1.0×0.5mm
1608	1.6×0.8mm
2012	2.0×1.2mm

(3) Structure code

(4) Varistor voltage

270	27×10 <sup>0</sup> V
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(5) Varistor voltage tolerance

K	±10%
M	±20%
N	±30%

(6) Packaging style

T	Taping
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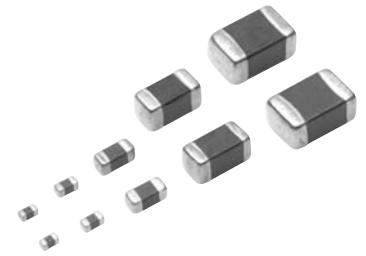
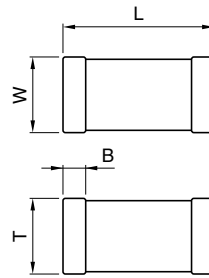
(7) Capacitance and TDK internal code

(5) Capacitance tolerance

N	±30%
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## SHAPES AND DIMENSIONS

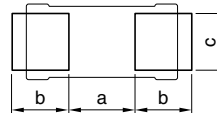
### 0402/0603/1005/1608/2012 TYPES



Dimensions in mm

Type	L	W	T	B min.	Weight (mg)typ.
0402	0.4±0.02	0.2±0.02	0.2±0.02	0.07	0.1
0603	0.6±0.03	0.3±0.03	0.3±0.03	0.1	0.2
1005	1.0±0.05	0.5±0.05	0.5±0.05	0.1	1.2
1608	1.6±0.1	0.8±0.1	0.8±0.1	0.2	5
2012	2.0±0.2	1.25±0.2	1.0±0.2	0.2	15

## RECOMMENDED PC BOARD PATTERN



Dimensions in mm

Type	a	b	c
0402	0.2	0.15 to 0.2	0.18 to 0.2
0603	0.25 to 0.35	0.2 to 0.3	0.25 to 0.35
1005	0.3 to 0.5	0.35 to 0.45	0.4 to 0.6
1608	0.6 to 0.8	0.6 to 0.8	0.6 to 0.8
2012	0.9 to 1.2	0.7 to 0.9	0.9 to 1.2

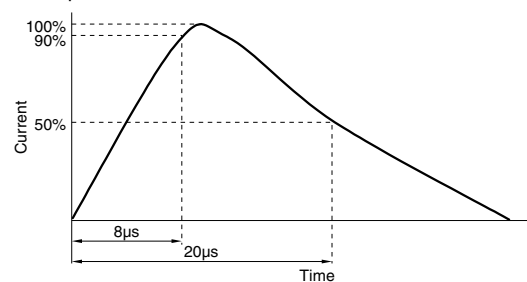
## ELECTRICAL CHARACTERISTICS

Part No.	Varistor voltage (Breakdown voltage) V <sub>1mA</sub> (V)[DC1mA]		Maximum continuous voltage (Rated voltage) V <sub>dc</sub> (V) max.	Clamping voltage V <sub>cl</sub> (V) [8/20μs]	Maximum energy E(Joule) [10/1000μs] max.	Maximum peak current I <sub>p</sub> (A) [8/20μs] max.	Capacitance C(pF) [1kHz, 1Vrms] typ.	Packaging quantities (Taping) (pieces/reel)	
0402 type									
AVRM0402C6R8NT101N	6.8	(4.76 to 8.84)	3.5	15[1A]	0.01	4	100 (70 to 130)	20,000	
AVRM0402C120MT330N	12	(9.6 to 14.4)	5.5	20[1A]	0.005	1	33 (23.1 to 43.9)		
0603 type									
AVRM0603C6R8NT331N	6.8	(4.76 to 8.84)	3.5	14[1A]	0.02	16	330 (231 to 429)	15,000	
AVRM0603C6R8NT101N	6.8	(4.76 to 8.84)	3.5	14[1A]	0.01	10	100 (70 to 130)		
AVRM0603C080MT101N	8	(6.4 to 9.6)	5.5	17[1A]	0.01	4	100 (70 to 130)		
AVRM0603C120MT101N	12.8	(10 to 15.6)	5.5	20[1A]	0.01	5	100 (70 to 130)		
AVR-M0603C120MTAAB	12	(9.6 to 14.4)	7.5	23[1A]	0.01	1	33		
AVRM0603C120MT150N	12.8	(10 to 15.6)	5.5	35[1A]	0.003	1	15 (10.5 to 19.5)		
AVRM0603C200MT150N	20	(16.0 to 24.0)	12	40[1A]	0.01	1	15 (10.5 to 19.5) [1MHz]		
1005 type									
AVRM1005C6R8NT331N	6.8	(4.76 to 8.84)	3.5	15[1A]	0.008	24	330 (231 to 429)	10,000	
AVRM1005C6R8NT101N	6.8	(4.76 to 8.84)	3.5	14[1A]	0.02	10	100 (70 to 130)		
AVR-M1005C080MTAAB	8	(6.4 to 9.6)	5.5	14[1A]	0.04	25	650		
AVR-M1005C080MTADB	8	(6.4 to 9.6)	5.5	14[1A]	0.04	25	480		
AVR-M1005C080MTABB	8	(6.4 to 9.6)	5.5	15[1A]	0.02	3	100		
AVR-M1005C080MTACB	8	(6.4 to 9.6)	5.5	19[1A]	0.01	1	33		
AVR-M1005C120MTACC	12	(9.6 to 14.4)	7.5	21[1A]	0.01	24	460 [1MHz]		
AVR-M1005C120MTAAB	12	(9.6 to 14.4)	7.5	20[1A]	0.05	10	130		
AVR-M1005C180MTAAB	18	(14.4 to 21.6)	11	30[1A]	0.06	16	120 [1MHz]		
AVRM1005C270KT101N	27	(24 to 30)	19	44[1A]	0.06	4	100 (70 to 130)		
AVR-M1005C270MTAAB	27	(21.6 to 32.4)	15	47[1A]	0.06	4	40		
AVR-M1005C270MTABB	27	(21.6 to 32.4)	15	49[1A]	0.05	1	15		
1608 type									
AVR-M1608C080MTAAB	8	(6.4 to 9.6)	5.5	15[2A]	0.09	30	650		4,000
AVR-M1608C120MT6AB	12	(9.6 to 14.4)	7.5	20[2A]	0.09	50	1050		
AVR-M1608C120MT2AB	12	(9.6 to 14.4)	7.5	20[2A]	0.06	15	400		
AVR-M1608C180MT6AB	18	(14.4 to 21.6)	11	30[2A]	0.1	30	600		
AVR-M1608C220KT6AB	22	(19.8 to 24.2)	16	34[2A]	0.1	30	560		
AVR-M1608C220KT2AB	22	(19.8 to 24.2)	16	37[2A]	0.03	10	210		
AVR-M1608C270KT6AB	27	(24 to 30)	19	42[2A]	0.1	48	430		
AVR-M1608C270KT2AB	27	(24 to 30)	19	42[2A]	0.1	20	160		
AVR-M1608C270KTACB	27	(24 to 30)	19	54[2A]	0.05	10	60		
AVRM1608C270KT800M	27	(24 to 30)	19	53[2A]	0.02	28	80 (64 to 96)		
AVR-M1608C270MTAAB	27	(21.6 to 32.4)	17	52[2A]	0.05	2	30		
AVR-M1608C270MTABB	27	(21.6 to 32.4)	17	52[2A]	0.05	2	15		
AVRM1608C390KT271N	39	(35 to 43)	28	69[2A]	0.1	78	270 (189 to 351)		
2012 type									
AVR-M2012C120MT6AB	12	(9.6 to 14.4)	7.5	20[5A]	0.2	60	1000	2,000	
AVR-M2012C220KT6AB	22	(19.8 to 24.2)	16	38[5A]	0.3	100	800		
AVR-M2012C390KT6AB	39	(35 to 43)	28	62[5A]	0.3	100	430		

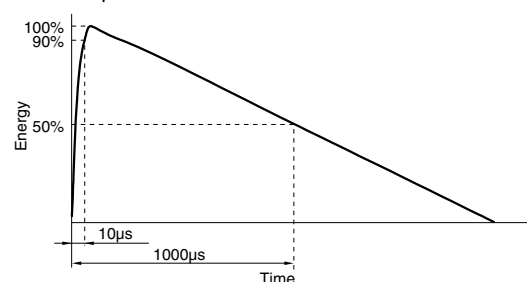
## TERMINOLOGY

Item	Unit	Terminology
Varistor voltage (Breakdown voltage)	V <sub>1mA</sub> (V)	Voltage measured across the varistor when DC1mA is applied.
Maximum continuous voltage (Rated voltage)	V <sub>dc</sub> (V)	Maximum DC voltage that can be applied continuously. Varistor leakage current: 50μA max. (Within the range of maximum allowable circuit voltage)
Clamping voltage	V <sub>cl</sub> (V)	Voltage appearing across the varistor when a pulse current (8/20μs*) of specified peak value is applied.
Maximum energy	E (Joule)	Maximum energy that can be absorbed without deteriorating varistor characteristics when an impulse (10/1000μs*) is applied once.
Maximum peak current	I <sub>p</sub> (A)	Maximum current that can be withstood without deteriorating varistor characteristics when an impulse current (8/20μs*) is applied once.
Capacitance	C (pF)	Capacitance measured at 1kHz (or 1MHz) of oscillator frequency and 1Vrms of oscillator voltage.

\*1 8/20μs test waveform



\*2 10/1000μs test waveform



• All specifications are subject to change without notice.

## AVRL TYPE

### PRODUCT IDENTIFICATION

AVRL	10	1A	3R3	F	T	A
(1)	(2)	(3)	(4)	(5)	(6)	(7)

(1) Series name

(2) Dimensions L×W

04	0.4×0.2mm
06	0.6×0.3mm
10	1.0×0.5mm
16	1.6×0.8mm

(3) Maximum continuous voltage

1A	10Vdc
1C	16Vdc
1E	25Vdc

(4) Capacitance

1R1	1.1pF
2R2	2.2pF
3R3	3.3pF
6R8	6.8pF

(5) Capacitance tolerance

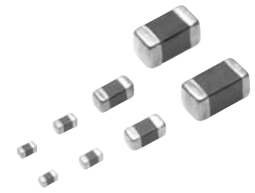
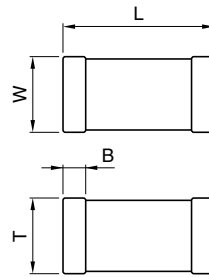
N	±0.3pF
D	±0.5pF
F	±1pF
G	±2pF

(6) Packaging style

T	Taping
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(7) Varistor voltage and TDK internal code

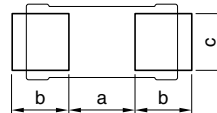
### SHAPES AND DIMENSIONS



Dimensions in mm

Type	L	W	T	B min.	Weight (mg)typ.
0402	0.4±0.02	0.2±0.02	0.2±0.02	0.07	0.1
0603	0.6±0.03	0.3±0.03	0.3±0.03	0.1	0.2
1005	1.0±0.05	0.5±0.05	0.5±0.05	0.1	1.2
1608	1.6±0.1	0.8±0.1	0.8±0.1	0.2	5

### RECOMMENDED PC BOARD PATTERN



Dimensions in mm

Type	a	b	c
0402	0.2	0.15 to 0.2	0.18 to 0.2
0603	0.25 to 0.35	0.2 to 0.3	0.25 to 0.35
1005	0.3 to 0.5	0.35 to 0.45	0.4 to 0.6
1608	0.6 to 0.8	0.6 to 0.8	0.6 to 0.8

### ELECTRICAL CHARACTERISTICS

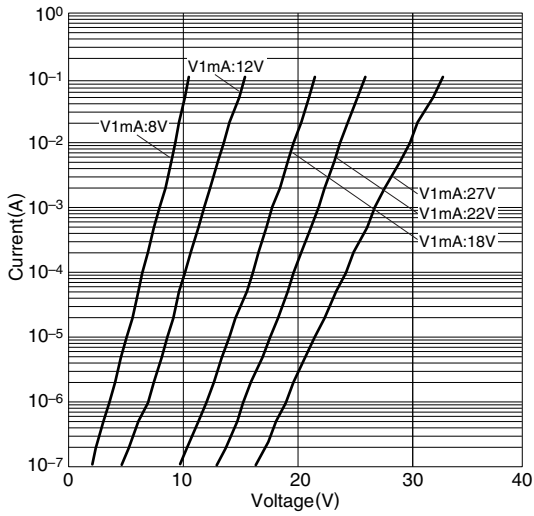
Part No.	Capacitance C(pF) [1MHz, 1Vrms]	Maximum continuous voltage (Rated voltage) Vdc(V) max.	Insulation resistance Rdc(MΩ) [3Vrms] min.	Varistor voltage V <sub>1mA</sub> (V)[DC1mA] typ.	Packaging quantities (Taping) (pieces/reel)
0402 type					
AVRL041E1R1NTA	1.1[0.8 to 1.4]	25	10	39	20,000
0603 type					
AVRL061E1R1NTA	1.1[0.8 to 1.4]	25	10	39	15,000
1005 type					
AVRL101A1R1NTA	1.1[0.8 to 1.4]	10	10	90	10,000
AVRL101A1R1NTB	1.1[0.8 to 1.4]	10	10	39	
AVRL101C2R2DTA	2.2[1.7 to 2.7]	16	10	90	
AVRL101A3R3FTA	3.3[2.3 to 4.3]	10	10	27	
AVRL101A6R8GTA	6.8[4.8 to 8.8]	10	10	27	
1608 type					
AVRL161A1R1NTA	1.1[0.8 to 1.4]	10	10	90	4,000
AVRL161A1R1NTB	1.1[0.8 to 1.4]	10	10	39	
AVRL161A3R3FTA	3.3[2.3 to 4.3]	10	10	27	
AVRL161A6R8GTA	6.8[4.8 to 8.8]	10	10	27	

### TERMINOLOGY

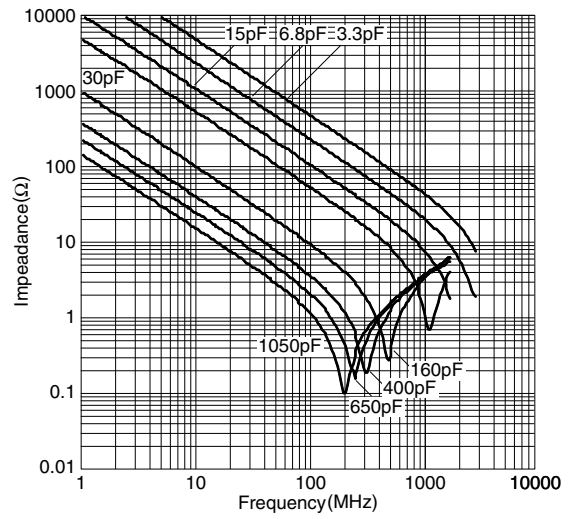
Item	Unit	Terminology
Capacitance	C (pF)	Capacitance measured at 1MHz of oscillator frequency and 1Vrms of oscillator voltage.
Maximum continuous voltage (Rated voltage)	Vdc (V)	Maximum DC voltage that can be applied continuously. Varistor leakage current: 50μA max. (Within the range of maximum allowable circuit voltage)
Insulation resistance	Rdc (MΩ)	Insulation resistance appearing across the varistor when specified voltage is applied.
Varistor voltage (Breakdown voltage)	V <sub>1mA</sub> (V)	Voltage measured across the varistor when DC1mA is applied.

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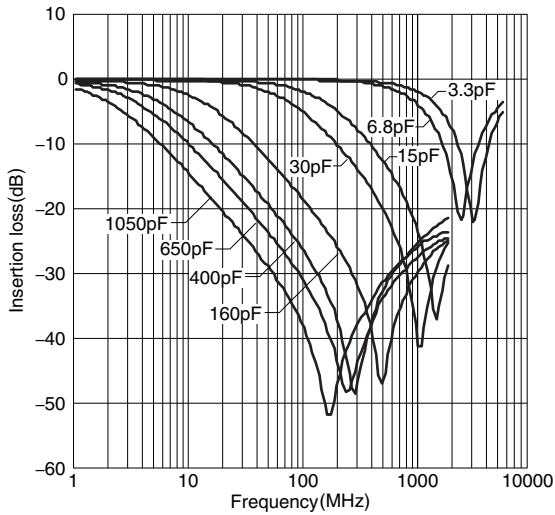
### TYPICAL ELECTRICAL CHARACTERISTICS CURRENT vs. VOLTAGE CHARACTERISTICS



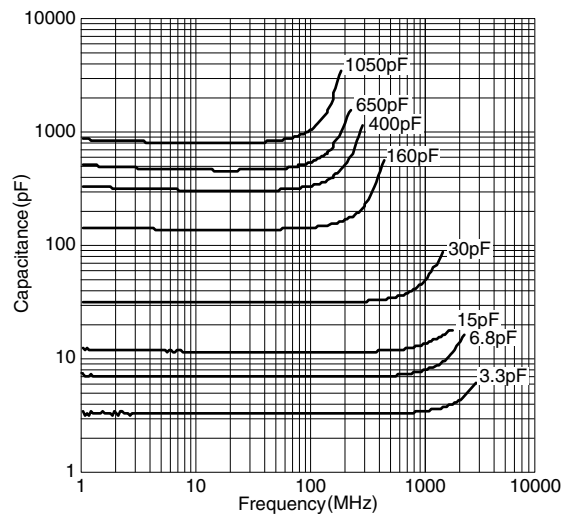
### IMPEDANCE vs. FREQUENCY CHARACTERISTICS



### TRANSMISSION CHARACTERISTICS



### CAPACITANCE vs. FREQUENCY CHARACTERISTICS



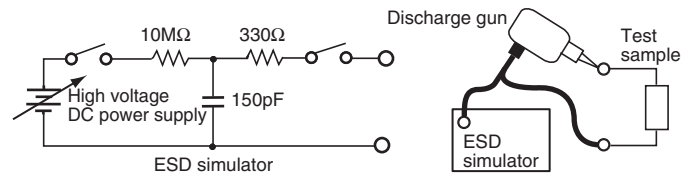


### ELECTROSTATIC DISCHARGE TESTS

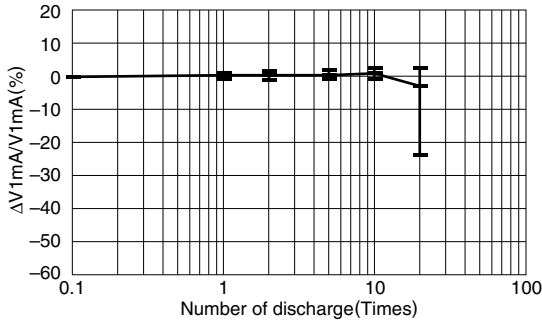
#### TEST CONDITIONS

150pF, 330Ω contact discharge  
Charged voltage /8kV, 0.1s interval

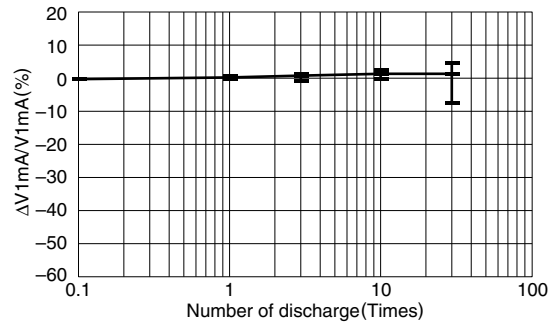
#### MEASURING CIRCUIT



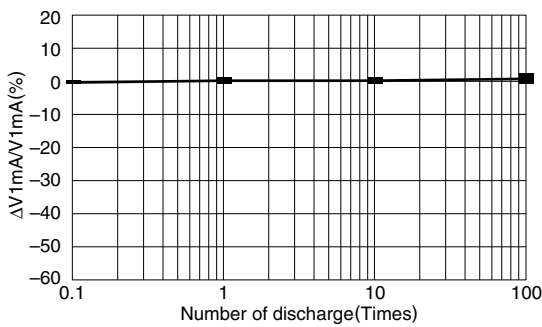
#### AVR-M0603 TYPE



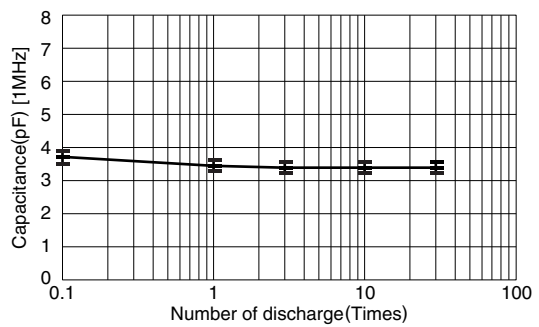
#### AVR-M1005 TYPE



#### AVR-M1608 TYPE

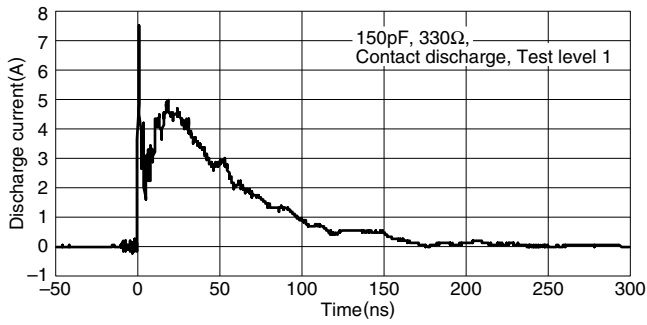


#### AVRL101A3R3F



**ELECTROSTATIC ABSORPTION CHARACTERISTICS**

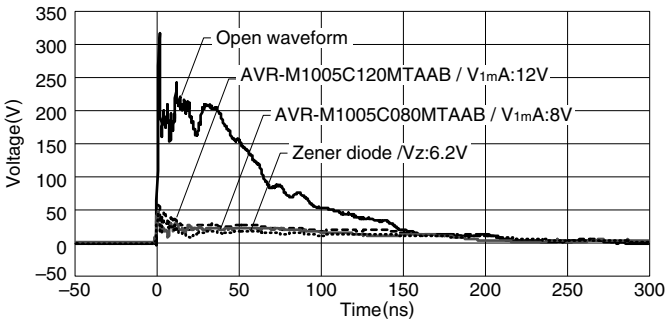
**DISCHARGE CURRENT WAVEFORM**



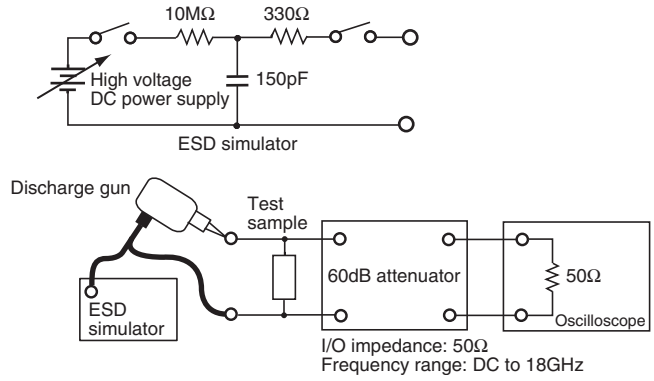
**WAVEFORM PARAMETERS [IEC61000-4-2]**

Test level	ESD Charge voltage (kV)	First peak current of discharge (A)	Rise time (ns)
1	2	7.5	0.7 to 1.0
2	4	15	0.7 to 1.0
3	6	22.5	0.7 to 1.0
4	8	30	0.7 to 1.0

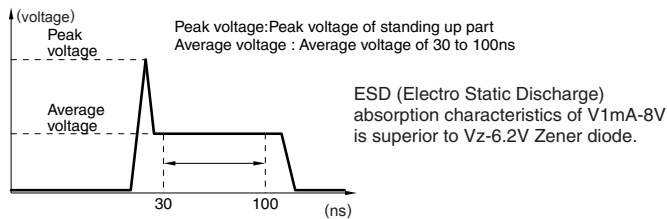
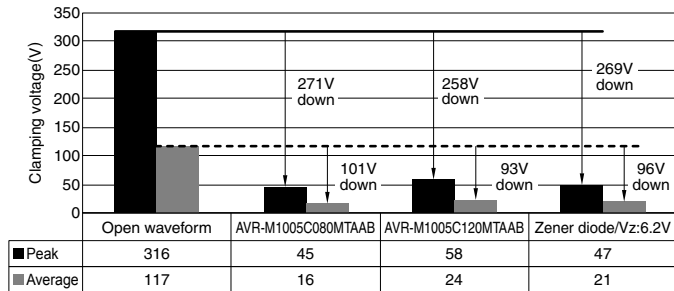
**DISCHARGE VOLTAGE WAVEFORM**



**MEASURING CIRCUIT**



**ESD ABSORPTION CHARACTERISTICS  
COMPARISON OF VARIOUS ELEMENTS**



• All specifications are subject to change without notice.

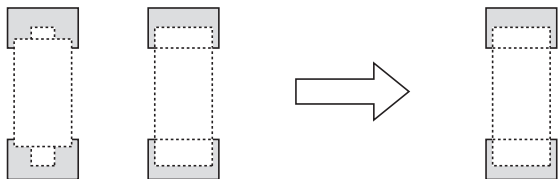
**MERITS OF REPLACEMENT FROM ZENER DIODE**

(1) Reduction in the number of parts

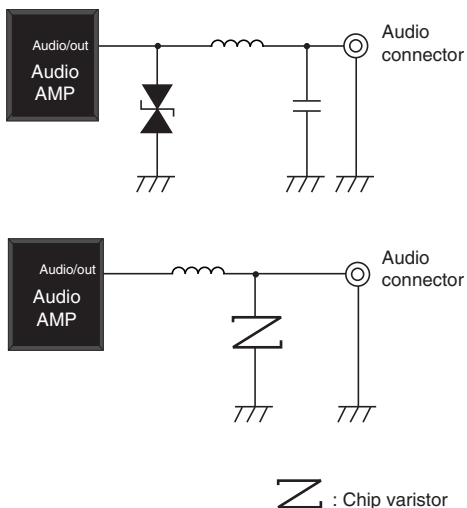
**REDUCTION EXAMPLES**

Zener diode+capacitor

Chip varistor

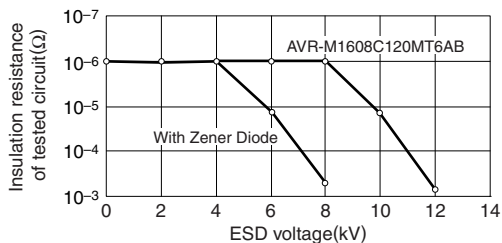


**EXAMPLE OF REPLACEMENT AT AUDIO TERMINAL**



(2) Improved electrostatic absorption capability

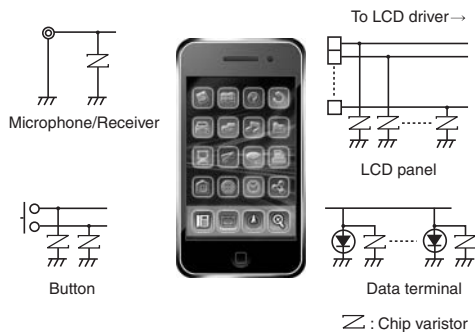
**COMPARE DATA OF CHIP VARISTOR AND ZENER DIODE ABOUT IC PROTECTION**



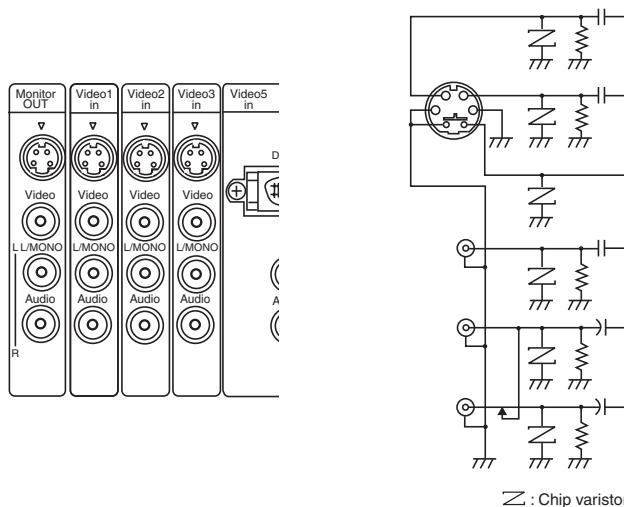
CMOS: D74HC04C  
 ESD generator : Noise Laboratory Co.,Ltd., ESS -630A  
 200pF-0Ω method model equipment  
 Contact type discharge  
 ESD applied point: Vcc-ground

**APPLICATION EXAMPLES**

**SMART PHONE**

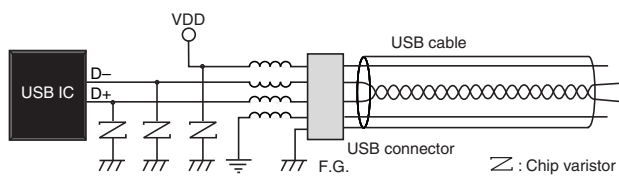


**AUDIO/VIDEO**

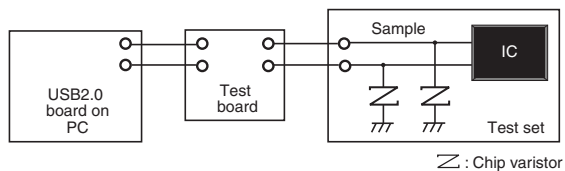


### APPLICATION EXAMPLES

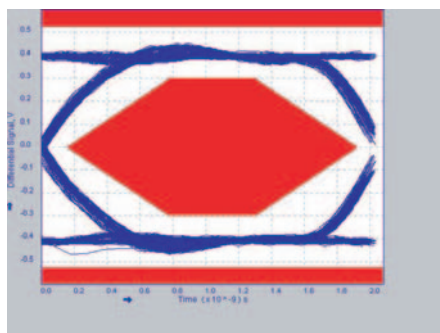
#### USB 2.0



#### MEASURING CIRCUIT

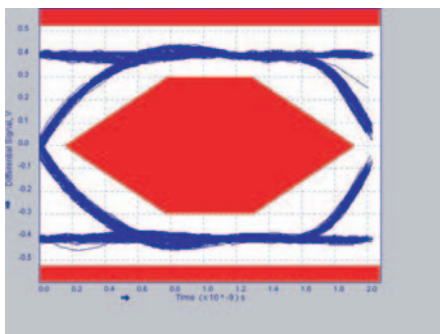


#### WITHOUT VARISTOR



#### WITH VARISTOR

##### AVRL101A3R3FTA (3.3pF)



##### AVRL101A6R8GTA (6.8pF)

